January 1996, Rev. C

FN7166

### Multiplexed-Input Video Amplifiers

## élantec.

The EL44XX family of video multiplexed-amplifiers offers a very quick 8ns switching time and low glitch

along with very low video distortion. The amplifiers have good gain accuracy even when driving low-impedance loads. To save power, the amplifiers do not require heavy loading to remain stable.

The EL4421 and EL4422 are two-input multiplexed amplifiers. The -inputs of the input stages are wired together and the device can be used as a pin-compatible upgrade from the MAX453.

The EL4441 and EL4442 have four inputs, also with common feedback. These may be used as upgrades of the MAX454.

The EL4443 and EL4444 are also 4-input multiplexed amplifiers, but both positive and negative inputs are wired separately. A wide variety of gain- and phase-switching circuits can be built using independent feedback paths for each channel.

The EL4421, EL4441, and EL4443 are internally compensated for unity-gain operation. The EL4422, EL4442, and EL4444 are compensated for gains of +2 or more, especially useful for driving back-matched cables.

The amplifiers have an operational temperature of -40°C to +85°C and are packaged in plastic 8- and 14-pin DIP and 8- and 14-pin SO.

The EL44XX multiplexed-amplifier family is fabricated with Elantec's proprietary complementary bipolar process which gives excellent signal symmetry and is very rugged.

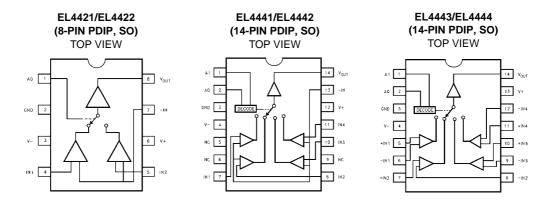
#### **Features**

- Unity or + 2-gain bandwidth of 80MHz
- · 70dB off-channel isolation at 4MHz
- Directly drives high-impedance or  $75\Omega$  loads
- 0.02% and 0.02° differential gain and phase errors
- · 8ns switching time
- < 100mV switching glitch
- 0.2% loaded gain error
- Compatible with ±3V to ±15V supplies
- 160mW maximum dissipation at ±5V supplies

## Ordering Information

PART NIMBER	TEMP. RANGE	PACKAGE	PKG. NO.
EL4421CN	-40°C to +85°C	8-Pin PDIP	MDP0031
EL4421CS	-40°C to +85°C	8-Pin SO	MDP0027
EL4422CN	-40°C to +85°C	8-Pin PDIP	MDP0031
EL4422CS	-40°C to +85°C	8-Pin SO	MDP0027
EL4441CN	-40°C to +85°C	14-Pin PDIP	MDP0031
EL4441CS	-40°C to +85°C	14-Pin SO	MDP0027
EL4442CN	-40°C to +85°C	14-Pin PDIP	MDP0031
EL4442CS	-40°C to +85°C	14-Pin SO	MDP0027
EL4443CN	-40°C to +85°C	14-Pin PDIP	MDP0031
EL4443CS	-40°C to +85°C	14-Pin SO	MDP0027
EL4444CN	-40°C to +85°C	14-Pin PDIP	MDP0031
EL4444CS	-40°C to +85°C	14-Pin SO	MDP0027

#### **Pinouts**



Manufactured under U.S. Patent No. 5,352,987

#### **Absolute Maximum Ratings** (T<sub>A</sub> = 25°C)

V+	Positive Supply Voltage	VLOGIC	Voltage at A0 or A14V to 6V
$V_S$	V+ to V- Supply Voltage	I <sub>IN</sub>	Current into any Input, Feedback, or Logic Pin 4mA
$V_{IN}$	Voltage at any Input or Feedback V+ to V-	I <sub>OUT</sub>	Output Current30mA
$V_{IN}$	Difference between Pairs of Inputs or Feedback 6V	$P_{D}$	Maximum Power Dissipation See Curves

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore:  $T_J = T_C = T_A$ 

## **Open-Loop DC Electrical Specifications**

Power supplies at  $\pm 5$ V,  $T_A = 25$ °C,  $R_L = 500\Omega$ , unless otherwise specified

PARAMETER	DESCRIPTION		MIN	TYP	MAX	UNITS	
Vos	Input Offset Voltage	'21, '41, and '43	-9	±3	9	mV	
		'22, '42, and '44	-7	±2	7		
IB	Input Bias Current, Positive Inputs On the '43 and '44	ly of the '21, '22, '41, '42, and All Inputs of	-12	-5	0	μΑ	
I <sub>FB</sub> Input Bias Cu	Input Bias Currents of Common	'21 and '22	-24	-10	0	μA	
	Feedback	'41 and '42	-48	-20	0	μA	
los	Input Offset Currents of the '43 and '4	4		60	350	nA	
E <sub>G</sub> Gair	Gain Error (Note 1)	'21 and '41 and '43		0.2	0.6	%	
		'22, '42 and '44		0.1	0.6	V/V	
A <sub>VOL</sub>	Open-Loop Gain (Note 1)	EL4443	350	500		V/V	
		EL4444	500	750		V/V	
V <sub>IN</sub>	Input Signal Range, EL4421 and EL4441 (Note 2)		±2.5	±3		V	
CMRR	Common-Mode Rejection Ratio, EL4443 and EL4444		70	90		dB	
PSRR	Power Supply Rejection Ratio V <sub>S</sub> from ±5V to ±15V		60	70		dB	
CMIR	Common-Mode Input Range EL4443 and EL4444 (Note 3)		±2.5	±3		V	
V <sub>OUT</sub>	Output Swing		±2.5	±3.5		V	
I <sub>SC</sub>	Output Short-Circuit Current		±40	±80		mA	
F <sub>T</sub>	Unselected Channel Feedthrough Attenuation (Note 1)	'21, '41, '43	70	80		dB	
		'22, '42, '44	55	64		dB	
I <sub>LOGIC</sub>	Input Current at A0 and A1 with Input = 0V and 5V		-16	-8	0	μA	
V <sub>LOGIC</sub>	Logic Valid High and Low Input Levels		0.8		2.0	V	
IS	Supply Current	EL4421 and EL4422		11	14	mA	
		EL4441, EL4442, EL4443, and EL4444	13	16			

#### NOTES:

- 1. The '21, '41, and '43 devices are connected for unity-gain operation with  $75\Omega$  load and an input span of ±1V. The '22, '42, and '44 devices are connected for a gain of +2 with a  $150\Omega$  load and a ±1V input span with  $R_F = R_G = 270\Omega$ .
- 2. The '21 and '41 devices are connected for unity gain with a ±3V input span while the output swing is measured.
- 3. CMIR is assured by passing the CMRR test at input voltage extremes.

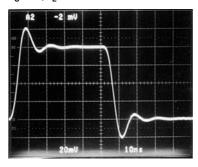
## **Closed-Loop AC Electrical Specifications**

Power supplies at ±5V.  $T_A$  = 25°C, for EL4421, EL4441, and EL4443  $A_V$  = +1 and  $R_L$  = 500 $\Omega$ , for EL4422, EL4442, and EL4444  $A_V$  = +2 and  $R_L$  = 150 $\Omega$  with  $R_F$  =  $R_G$  = 270 $\Omega$  and  $C_F$  = 3pF; for all  $C_L$  = 15pF

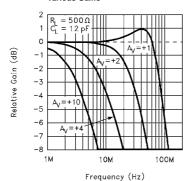
PARAMETER	DESC	RIPTION	MIN	TYP	MAX	UNITS
BW - 3dB	-3dB Small-Signal Bandwidth	EL4421, '41, '43		80		MHz
		EL4422, '42, '44		65		MHz
BW ± 0.1dB	0.1dB Flatness Bandwidth			10		MHz
Peaking	Frequency Response Peaking			0.5		dB
SR	Slewrate, $V_{OUT}$ between -2.5V and +2.5V, $V_{S} = \pm 12V$	EL4421, EL4441, EL4443	150	200		V/µsec
		EL4422, EL4442, EL4444	180	240		V/µsec
V <sub>N</sub>	Input-Referred Noise Voltage Density	EL4421, EL4441, EL4443		18		nV/√Hz
		EL4422, EL4442, EL4444		14		nV/√Hz
d <sub>G</sub>	Differential Gain Error, V <sub>OFFSET</sub> between -0.7V and +0.7V	EL4421, '41, '43 (V <sub>S</sub> = ±12V)		0.01		%
		EL4421, '41, '43 (V <sub>S</sub> = ±5V)		0.10		%
		EL4422, '42, '44 (V <sub>S</sub> = ±12V)		0.02		%
		EL4422, '42, '44 (V <sub>S</sub> = ±5V)		0.11		%
dø	Differential Phase Error, VOFFSET between -0.7V and +0.7V	EL4421, '41, '43 (V <sub>S</sub> = ±12V)		0.01		۰
		EL4421, '41, '43 (V <sub>S</sub> = ±5V)		0.1		۰
		EL4422, '42, '44 (V <sub>S</sub> = ±12V)		0.02		۰
		EL4422, '42, '44 (V <sub>S</sub> = ±5V)		0.15		0
T <sub>MUX</sub>	Multiplex Delay Time, Logic Threshold to 50% Signal Change	EL4421, '22		8		nsec
		EL4441, '42, '43, '44		12		nsec
V <sub>GLITCH</sub>	Peak Multiplex Glitch	EL4421, '22		70		mV
		EL4441, '42, '43, '44		100		mV
ISO	Channel Off Isolation at 3.58MHz (See Text)	EL4421, EL4441, EL4443		76		dB
		EL4422, EL4442, EL4444		63		dB

## **Typical Performance Curves**

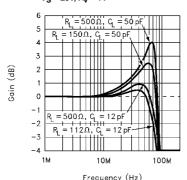
EL4421, EL4441, and EL4443 Small-Signal Transient Response  $V_S = \pm 5V$ ,  $R_L = 500\Omega$ 



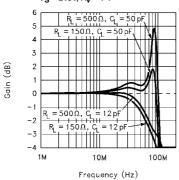
EL4421, EL4441, and EL4443 Frequency Response for Various Gains



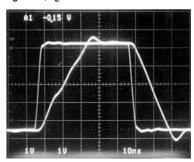
EL4421, EL4441, and EL4443 Frequency Response for Various Loads  $V_S=\pm 5V$ ,  $A_V=+1$ 



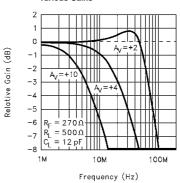
Frequency Response for Various Loads  $V_S = \pm 15V$ ,  $A_V = \pm 1$ 



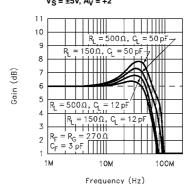
EL4421, EL4441, and EL4443 Large-Signal Response  $V_S = \pm 12V$ ,  $R_L = 500\Omega$ 



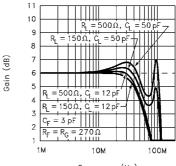
EL4422, EL4442, and EL4444 Frequency Response for Various Gains



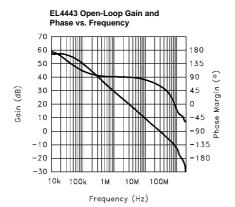
EL4422, EL4442, and EL4444 Frequency Response for Various Loads  $V_S = \pm 5V$ ,  $A_V = +2$ 



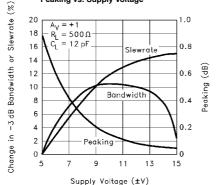
EL4422, EL4442, and EL4444 Frequency Response for Various Loads  $V_S = \pm 15V$ ,  $A_V = +2$ 



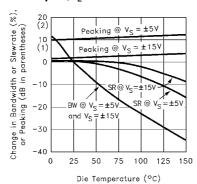
## Typical Performance Curves (Continued)



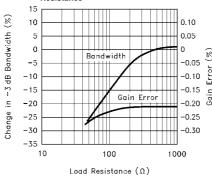
EL4421, EL4441, and EL4443 -3dB Bandwidth, Slewrate, and Peaking vs. Supply Voltage



EL4421, EL4441, and EL4443 Bandwidth, Slewrate, and Peaking vs. Temperature, AV = +1, RL =500 $\Omega$ 



EL4421, EL4441, and EL4443 -3dB Bandwidth and Gain Error vs. Load Resistance



60 180 50 40 90 <u></u> 30 45 Gain (dB) 20 0 10 0 -10 -135 -20 180

EL4444 Open-Loop Gain and

EL4422, EL4442, and EL4444
-3dB Bandwidth, Slewrate, and Peaking vs. Supply Voltage

10M

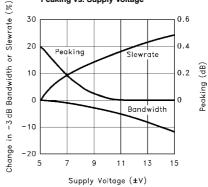
100M

1M

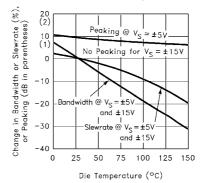
Frequency (Hz)

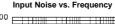
10K

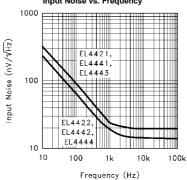
100K



EL4422, EL4442, and EL4444 Bandwidth, Slewrate, and Peaking vs. Temperature,  $A_V = +2$ ,  $R_L = 150\Omega$ ,  $R_I = R_G = 270\Omega$ ,  $C_F = 3pF$ 

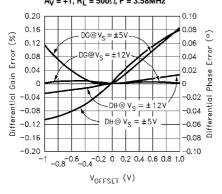




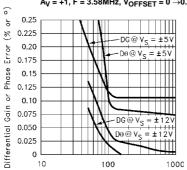


## Typical Performance Curves (Continued)

EL4421, EL4441, and EL4443 Differential Gain and Phase Errors, vs. Input Offset,  $A_V = +1$ ,  $R_L = 500\Omega$ , F = 3.58MHz



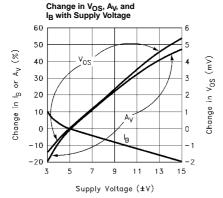
EL4421, EL4441, and EL4443 Differential Gain and Phase Error vs. Load Resistance;  $A_V=+1, F=3.58 MHz, V_{OFFSET}=0 \rightarrow 0.714 V$ 



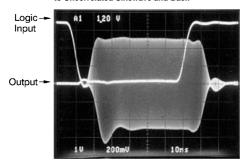
100  $R_{\mathsf{LOAD}}$  ( $\Omega$ )

0.025

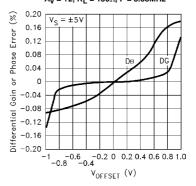
10



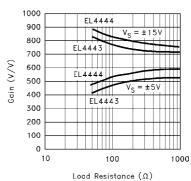
Switching Waveforms Switching from Grounded Input to Uncorrelated Sinewave and Back



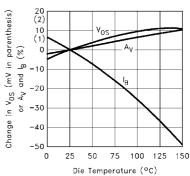
EL4422, EL4442, and EL4444 Differential Gain and Phase Error vs. Input Offset;  $A_V = +2$ ,  $R_L = 150\Omega$ , F = 3.58MHz



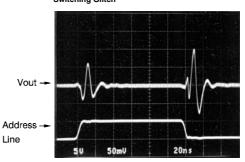
EL4443 and EL4444 Open-Loop Gain vs. Load Resistance



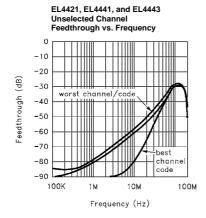
Change in  $\mathrm{V}_{\mathrm{OS}},\,\mathrm{I}_{\mathrm{B}},\,\mathrm{and}\,\,\mathrm{A}_{\mathrm{V}}\,\mathrm{vs.}$  Temperature

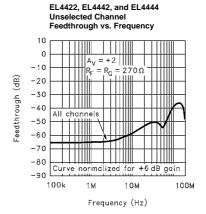


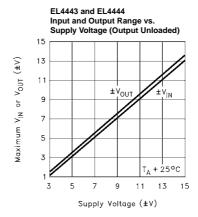
Channel-to-Channel **Switching Glitch** 

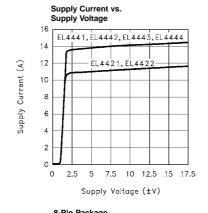


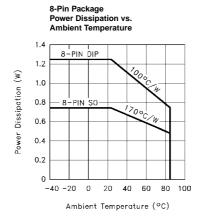
## Typical Performance Curves (Continued)

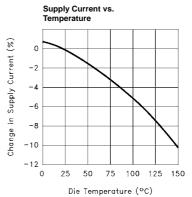


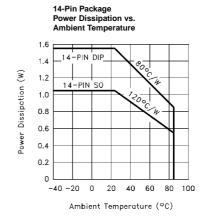












## Applications Information

#### **General Description**

The EL44XX family of video mux-amps are composed of two or four input stages whose inputs are selected and control an output stage. One of the inputs is active at a time and the circuit behaves as a traditional voltage-feedback op-amp for that input, rejecting signals present at the unselected inputs. Selection is controlled by one or two logic inputs.

The EL4421, EL4422, EL4441, and EL4442 have all -inputs wired in parallel, allowing a single feedback network to set the gain of all inputs. These devices are wired for positive gains. The EL4443 and EL4444, on the other hand, have all +inputs and -inputs brought out separately so that the input stage can be wired for independent gains and gain polarities with separate feedback networks.

The EL4421, EL4441, and EL4443 are compensated for unity-gain stability, while the EL4422, EL4442, and EL4444 are compensated for a fed-back gain of +2, ideal for driving back-terminated cables or maintaining bandwidth at higher fed-back gains.

#### Switching Characteristics

The logic inputs work with standard TTL levels of 0.8V or less for a logic 0 and 2.0V or more for a logic 1, making them compatible for TTL and CMOS drivers. The ground pin is the logic threshold biasing reference. The simplified input circuitry is shown in Figure 1 below.

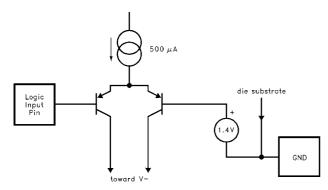
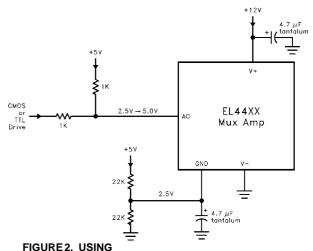


FIGURE 1. SIMPLIFIED LOGIC INPUT CIRCUITRY

The ground pin draws a maximum DC current of  $6\mu A$ , and may be biased anywhere between (V-) +2.5V and (V+) -3.5V. The logic inputs may range from (V-)+2.5V to V+, and are additionally required to be no more negative than V(Gnd pin)-4V and no more positive than V(Gnd pin)+6V.

For example, within these constraints, we can power the EL44XX's from +5V and +12V without a negative supply by using these connections.



THE EL44XX MUX AMPS WITH +5V AND +12V SUPPLIES

The logic input(s) and ground pin are shifted 2.5V above system ground to correctly bias the mux-amp. Of course, all the signal inputs and output will have to be shifted 2.5V above system ground to ensure proper signal path biasing.

A final caution: the ground pin is also connected to the IC's substrate and frequency compensation components. The ground pin must be returned to system ground by a short wire or nearby bypass capacitor. In Figure 2, the  $22k\Omega$  resistors also serve to isolate the bypassed ground pin from the +5V supply noise.

#### Signal Amplitudes

Signal input and output voltages must be between (V-)+2.5V and (V+)-2.5V to ensure linearity. Additionally, the differential voltage on any input stage must be limited to  $\pm 6V$  to prevent damage. In unity-gain connections, any input could have  $\pm 3V$  applied and the output would be at  $\pm 3V$ , putting us at our 6V differential limit. Higher-gain circuit applications divide the output voltage and allow for larger outputs. For instance, at a gain of +2 the maximum input is again  $\pm 3V$  and the output swing is  $\pm 6V$ . The EL4443 or EL4444 can be wired for inverting gain with even more amplitude possible.

The output and positive inputs respond to overloading amplitudes correctly; that is, they simply clamp and remain monotonic with increasing +input overdrive. A condition exists, however, where the -input of an active stage is overdriven by large outputs. This occurs mainly in unity-gain connections, and only happens for negative inputs. The overloaded input cannot control the feedback loop correctly and the output can become non-monotonic. A typical scenario has the circuit running on ±5V supplies, connected for unity gain, and the input is the maximum ±3V. Negative input extremes can cause the output to jump from -3V to

around -2.3V. This will never happen if the input is restricted to ±2.5V, which is the guaranteed maximum input compliance with ±5V supplies, and is not a problem with greater supply voltages. Connecting the feedback network with a divider will prevent the overloaded output voltage from being large enough to overload the -input and monotonic behavior is assured. In any event, keeping signals within guaranteed compliance limits will assure freedom from overload problems.

The input and output ranges are substantially constant with temperature.

#### **Power Supplies**

The mux-amps work well on any supplies from  $\pm 3V$  to  $\pm 15V$ . The supplies may be of different voltages as long as the requirements of the Gnd pin are observed (see the Switching Characteristics section for a discussion). The supplies should be bypassed close to the device with short leads.  $4.7\mu F$  tantalum capacitors are very good, and no smaller bypasses need be placed in parallel. Capacitors as small as  $0.01\mu F$  can be used if small load currents flow.

Single-polarity supplies, such as +12V with +5V can be used as described in the Switching Characteristics section. The inputs and outputs will have to have their levels shifted above ground to accommodate the lack of negative supply.

The dissipation of the mux-amps increases with power supply voltage, and this must be compatible with the package chosen. This is a close estimate for the dissipation of a circuit:

$$P_D = 2V_S \times I_S, max + (V_S - V_O) \times V_O / R_{PAR}$$

Where

 $I_S$ , max is the maximum supply current

V<sub>S</sub> is the ± supply voltage (assumed equal)

Vo is the output voltage

R<sub>PAR</sub> is the parallel of all resistors loading the output

For instance, the EL4422 draws a maximum of 14mA and we might require a 2V peak output into  $150\Omega$  and a  $270\Omega$  +270 $\Omega$  feedback divider. The  $R_{PAR}$  is 117 $\Omega$ . The dissipation with  $\pm 5V$  supplies is 191mW. The maximum Supply voltage that the device can run on for a given  $P_D$  and the other parameter is

$$V_{S}$$
, max =  $(P_D + V_O^2/R_{PAR})/2I_S + V_O/R_{PAR}$ 

The maximum dissipation a package support is

$$P_D$$
, max =  $(T_D$ , max- $T_A$ , max)/ $R_{TH}$ 

Where

T<sub>D</sub>, max is the maximum die temperature, 150°C for reliability, less to retain optimum electrical performance

T<sub>A</sub>, max is the ambient temperature, 70° for commercial and 85°C for industrial range

R<sub>TH</sub> is the thermal resistance of the mounted package, obtained from data sheet dissipation curves

The most difficult case is the SO-8 package. With a maximum die temperature of  $150^{\circ}$ C and a maximum ambient temperature of  $85^{\circ}$ , the  $65^{\circ}$  temperature rise and package thermal resistance of  $170^{\circ}$ /W gives a maximum dissipation of 382mW. This allows a maximum supply voltage of  $\pm 9.2$ V for the EL4422 operated in our example. If the EL4421 were driving a light load ( $R_{PAR} \rightarrow \infty$ ), it could operate on  $\pm 15$ V supplies at a  $70^{\circ}$  maximum ambient.

The EL4441 through EL4444 can operate on ±12V supplies in the SO package, and all parts can be powered by ±15V supplies in DIP packages.

#### **Output Loading**

The output stage of the mux-amp is very powerful, and can source 80mA and sink 120mA. Of course, this is too much current to sustain and the part will eventually be destroyed by excessive dissipation or by metal traces on the die opening. The metal traces are completely reliable while delivering the 30mA continuous output given in the Absolute Maximum Ratings table in this data sheet, or higher purely transient currents.

Gain or gain accuracy degrades only 10% from no load to  $100\Omega$  load. Heavy resistive loading will degrade frequency response and video distortion only a bit, becoming noticeably worse for loads <  $100\Omega$ .

Capacitive loads will cause peaking in the frequency response. If capacitive loads must be driven, a small-valued series resistor can be used to isolate it.  $12\Omega$  to  $51\Omega$  should suffice. A  $22\Omega$  series resistor will limit peaking to 2.5dB with even a 220pF load.

#### Input Connections

The input transistors can be driven from resistive and capacitive sources but are capable of oscillation when presented with an inductive input. It takes about 80nH of series inductance to make the inputs actually oscillate, equivalent to four inches of unshielded wiring or about 6 of unterminated input transmission line. The oscillation has a characteristic frequency of 500MHz.

Often simply placing one's finger (via a metal probe) or an oscilloscope probe on the input will kill the oscillation. Normal high-frequency construction obviates any such problems, where the input source is reasonably close to the mux-amp input. If this is not possible, one can insert series resistors of around  $51\Omega$  to de-Q the inputs.

#### Feedback Connections

A feedback divider is used to increase circuit gain, and some precautions should be observed. The first is that parasitic capacitance at the -input will add phase lag to the feedback path and increase frequency response peaking or even cause oscillation. One solution is to choose feedback resistors whose parallel value is low. The pole frequency of the feedback network should be maintained above at least 200MHz. For a 3pF parasitic, this requires that the feedback divider have less than  $265\Omega$  impedance, equivalent to two  $510\Omega$  resistors when a gain of +2 is desired. Alternatively, a small capacitor across RF can be used to create more of a frequency-compensated divider. The value of the capacitor should match the parasitic capacitance at the -input. It is also practical to place small capacitors across both the feedback resistors (whose values maintain the desired gain) to swamp out parasitics. For instance, two 10pF capacitors across equal divider resistors will dominate parasitic effects and allow a higher divider resistance.

The other major concern about the divider concerns unselected-channel crosstalk. The differential input impedance of each input stage is around  $200 k\Omega$ . The unselected input's signal sources thus drive current through that input impedance into the feedback divider, inducing an unwanted output. The gain from unselected input to output, the crosstalk attenuation, if  $R_F/R_{IN}$ . In unity-gain connection the feedback resistor is  $0\Omega$  and very little crosstalk is induced. For a gain of +2, the crosstalk is about -60dB.

#### Feedthrough Attenuation

The channels have different crosstalk levels with different inputs. Here is the typical attenuation for all combinations of inputs for the mux-amps at 3.58MHz:

#### FEEDTHROUGH OF EL4441 AND EL4443 AT 3.58MHz

SELECTINPUTS, A1 A0	IN1	IN2	IN3	IN4
00	Selected	-77dB	-90dB	-92dB
01	-80dB	Selected	-77dB	-90dB
10	-101dB	-76dB	Selected	-66dB
11	-96dB	-84dB	-66dB	Selected

#### FEEDTHROUGH OF EL4421 AT 3.58MHz

CHANNEL SELECT INPUT, A0	IN1	IN2
0	Selected	-88dB
1	-93dB	Selected

#### Switching Glitches

The output of the mux-amps produces a small "glitch' voltage in response to a logic input change. A peak amplitude of only about 90mV occurs, and the transient settles out in 20ns. The glitch does not change amplitude with different gain settings.

With the four-input multiplexers, when two logic inputs are simultaneously changed, the glitch amplitude doubles. The increase can be a avoided by keeping transitions at least 6ns apart. This can be accomplished by inserting one gate delay in one of the two logic inputs when they are truly synchronous.

All Intersil U.S. products are manufactured, assembled and tested utilizing ISO9000 quality systems. Intersil Corporation's quality certifications can be viewed at www.intersil.com/design/quality

Intersil products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design, software and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.

For information regarding Intersil Corporation and its products, see www.intersil.com